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- 406 photonic and semiconductor and substrate of substra					0000/04/15 14:41
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		substrate	US-PGPUB;	
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		semiconductor and substrate	US-PGPUB; EPO; JPO;	
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		or band\$1gap\$2))	EPO; JPO; DERWENT;	
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-	67	(first near2 dielectric) and (second near2 dielectric) and (photonic adj (crystal\$4	USPAT; US-PGPUB;	2003/04/17 17:50
		or band\$1gap\$2))	EPO; JPO;	
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		or band\$1gap\$2))	EPO; JPO; DERWENT;	
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-	2	(first near3 dielectric) and (second near3	USPAT;	2003/04/17 18:25
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		and substrate	US-PGPUB; EPO; JPO;	
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		semiconductor and substrate	US-PGPUB;	
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		substrate	US-PGPUB;	
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	50	substrate	US-PGPUB;	2003/04/24 14.20
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-	71			2003/04/24 15:19
		and photonic and semiconductor and substrate	US-PGPUB; EPO; JPO;	
		Substrate	DERWENT;	
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	30	semiconductor and substrate	US-PGPUB;	2003/03/01 10:20
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-	1 6	("5739796").PN. (("5999308") or ("5990850") or ("6064511")	USPAT USPAT	2004/04/18 19:45 2004/04/18 20:01
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